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## Dual-Mode Manipulating Multicenter Photoluminescence in a Single-Phased $\text{Ba}_9\text{Lu}_2\text{Si}_6\text{O}_{24}:\text{Bi}^{3+}, \text{Eu}^{3+}$ Phosphor to Realize White Light/Tunable Emissions

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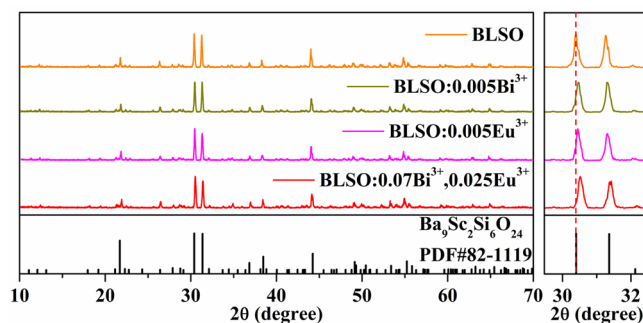
A  $\text{Bi}^{3+}$  and  $\text{Eu}^{3+}$  ion co-doped  $\text{Ba}_9\text{Lu}_2\text{Si}_6\text{O}_{24}$  single-phased phosphor was synthesized successfully via a conventional high-temperature solid-state reaction. X-ray diffraction, crystal structure analysis, diffuse reflectance and luminescent spectra, quantum efficiency measurements, and thermal stability analysis were applied to investigate the phase, structure, luminescent and thermal stability properties. From the analyses of the crystal structure and luminescent spectra, we observed four discernible  $\text{Bi}^{3+}$  luminescent centers with peaks at ~363.3, ~403.1, ~437.7, and ~494.5 nm. Moreover, due to the complex energy transfer processes among these  $\text{Bi}^{3+}$  centers, their relative emission intensity tightly depended on the incident excitation wavelength. Interestingly, the as-prepared phosphor could generate warm white light/tunable emission by changing the concentration of  $\text{Eu}^{3+}$  ions or adjusting the excitation wavelength. The energy transfer mechanism from  $\text{Bi}^{3+}$  to  $\text{Eu}^{3+}$  was confirmed via an electric dipole-dipole interaction, the energy transfer efficiencies ( $\eta_T$ ) from  $\text{Bi}^{3+}$  to  $\text{Eu}^{3+}$  were 50.84% and 40.17% monitoring at 410 and 485 nm, respectively. The internal quantum efficiency of the optimized  $\text{Ba}_9\text{Lu}_2\text{Si}_6\text{O}_{24}:\text{Bi}^{3+}, \text{Eu}^{3+}$  phosphor was calculated to be 42.6%. In addition, the configurational coordinate model was carried out to explain the energy decrease of the phonon-electron coupling effect.

Recently, phosphor materials have attained great achievement and progress in various fields, including solid-state lighting, optical temperature sensors, flat panel displays, solar cells, and optical biomarkers<sup>1–6</sup>. As next-generation lighting devices, phosphor-converted white light-emitting diodes (w-LEDs) have received much more attention since w-LEDs provide extraordinary superiorities, such as low electric consumption, high electro-optical conversion efficiency, high brightness, good stability, fast response, and environmental friendliness<sup>7–10</sup>. Until now, combining blue-emitting InGaN-based LED chips and yellow-emitting  $\text{Y}_3\text{Al}_5\text{O}_{12}:\text{Ce}^{3+}$  phosphors to make white light emission is one of the simplest and most efficient ways for commercial application<sup>11,12</sup>. However, such a combination shows a poor color rendering index (CRI < 80) and a high correlated color temperature (CCT > 4500 K) due to the lack of red-light contribution, which limits vivid applications<sup>13,14</sup>. To overcome the above mentioned problems, another improvement method is to employ near ultraviolet (near-UV) emitting LED chips (300–410 nm) coated with trichromatic phosphors. Unfortunately, the trichromatic phosphor system produces several inevitable problems, including complex coating, fluorescence reabsorption between different components, and non-uniformity of the luminescence properties, resulting in the degradation of luminous efficiency, increased manufacturing costs and a time-dependent shift of the color point<sup>15,16</sup>. To circumvent these drawbacks, a single-phased phosphor, which is fabricated by co-doping the sensitizer and activator ions into an appropriate host, with white light emission for near-UV pumped w-LEDs would be favorable alternative<sup>17</sup>.

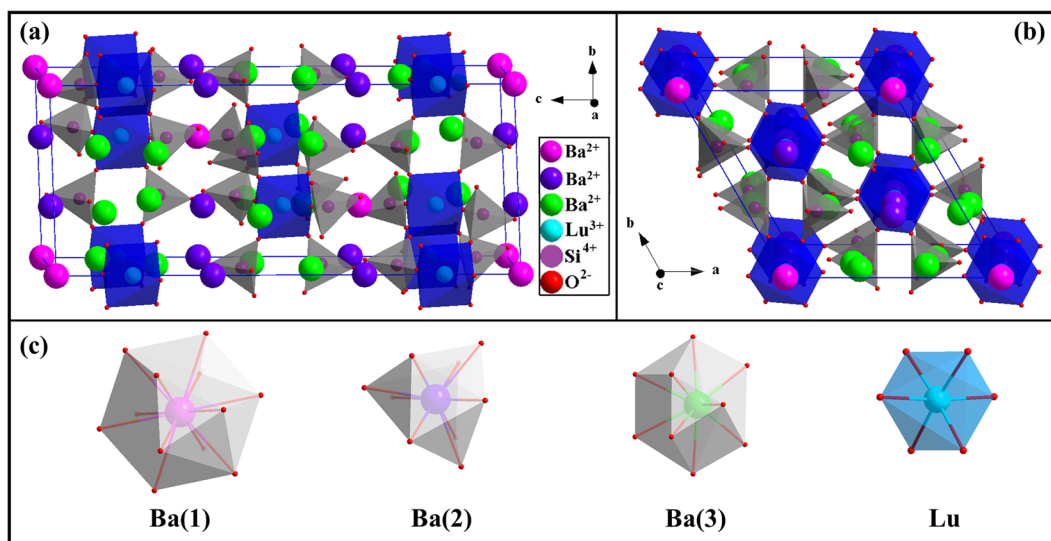
Silicate materials are inexpensive and readily available, and silicate-based phosphor materials serve as promising luminescent materials in the use of phosphor-converted w-LEDs because of their structural diversity,

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**Figure 2.** The XRD patterns of blank BLSO, BLSO:0.005Bi<sup>3+</sup>, BLSO:0.005Eu<sup>3+</sup>, and BLSO:0.07Bi<sup>3+</sup>,0.025Eu<sup>3+</sup> phosphors and the standard pattern (PDF#82-1119).

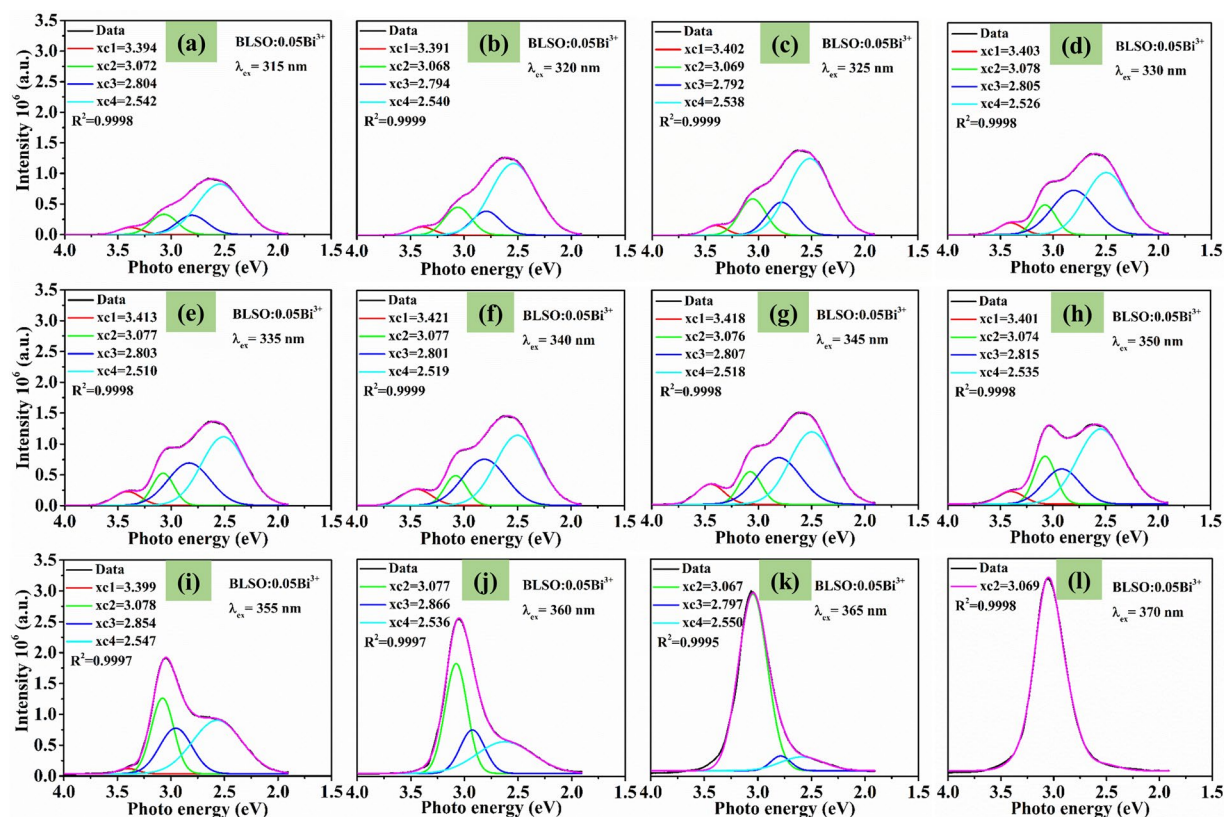


**Figure 3.** Crystal structure of BLSO unit cell viewed from the a-axis (a) and c-axis (b). The coordination environments of Ba(1), Ba(2), Ba(3) and Lu sites (c).

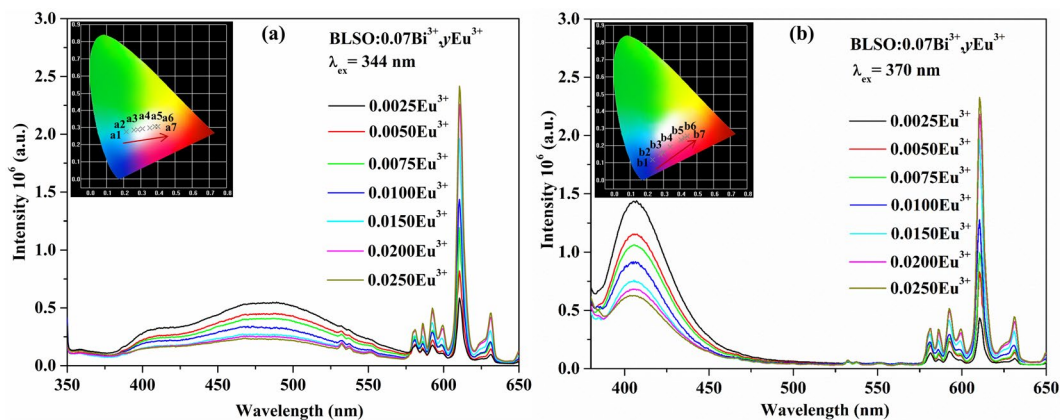
in which the smaller tetrahedral SiO<sub>4</sub> units and the larger octahedral LuO<sub>6</sub> units are corner-shared as SiO<sub>4</sub>-LuO<sub>6</sub>-SiO<sub>4</sub>-LuO<sub>6</sub>, forming a rigid three-dimensional network<sup>7</sup>. In the crystal structure, the Lu<sup>3+</sup> ions are located at the 6c Wyckoff position with 6-fold coordination, evolving a distorted LuO<sub>6</sub> octahedron that has two different Lu-O bond lengths<sup>20</sup>. While the Ba<sup>2+</sup> ions are designated in three independent sites: Ba(1) at the 3a Wyckoff position with 12-fold coordination, Ba(2) at the 6c Wyckoff position with 9-fold coordination and Ba(3) at the 18f Wyckoff position with 10-fold coordination, forming three different distorted polyhedra with different Ba-O bond lengths. For easy distinguish, we can define the three distinct types of Ba sites and one Lu site as Ba(1), Ba(2), Ba(3) and Lu, respectively, and all these sites can be substituted by Bi<sup>3+</sup> or Eu<sup>3+</sup> ions. For the Ba atom sites, such as the 12-fold coordination Ba(3) site, Bi<sup>3+</sup> ( $r = 1.45 \text{ \AA}$ ) and Eu<sup>3+</sup> ( $r = 1.23 \text{ \AA}$ ) ions are smaller than Ba<sup>2+</sup> ( $r = 1.61 \text{ \AA}$ ) ions, and therefore, the Bi<sup>3+</sup> and Eu<sup>3+</sup> ions are expected to randomly substitute the Ba<sup>2+</sup> sites. This result can be extended to the other Ba<sup>2+</sup> ions. However, for the Lu atom site with 6-fold coordination, Bi<sup>3+</sup> ( $r = 1.02 \text{ \AA}$ ) and Eu<sup>3+</sup> ( $r = 0.947 \text{ \AA}$ ) ions are bigger than Lu<sup>3+</sup> ( $r = 0.861 \text{ \AA}$ ) ions. According to Vegard's law, a complete solid solution should form if the size difference of ions is in the range of  $\pm 15\%$ <sup>25</sup>. Therefore, Bi<sup>3+</sup> and Eu<sup>3+</sup> ions can also randomly substitute the Lu site.

**Luminescence Properties of Bi<sup>3+</sup> Single-Doped Ba<sub>9</sub>Lu<sub>2</sub>Si<sub>6</sub>O<sub>24</sub> Phosphor.** Upon different excitation wavelengths, the Bi<sup>3+</sup> single-doped BLSO sample shows different luminescence features. Figure 4a shows the photoluminescence and excitation spectra of the BLSO: 0.05Bi<sup>3+</sup> sample excited at 335/370 nm and monitored at 410/485 nm, respectively. There is no luminescence from blank BLSO, and thus, the observed different luminescence features should come from the Bi<sup>3+</sup> ions. Under excitation of 370 nm, the BLSO:0.05Bi<sup>3+</sup> sample exhibits a symmetric broad blue emission band ranging from 380 to 500 nm with a maximum value at 410 nm. Monitoring the emission at 410 nm produces the excitation spectrum, which consists of two broad absorption bands with peaks at around 335 and 370 nm. Upon 335 nm excitation, BLSO:0.05Bi<sup>3+</sup> presents a different emission band ranging from 350 to 650 nm with three bands peaking at about 365, 410 and 485 nm. Figure 4b shows the excitation spectrum monitored at 485 nm, which can be deconvoluted into three symmetric absorption bands centered at 3.905 eV (317.5 nm), 3.807 eV (325.7 nm), and 3.616 eV (342.9 nm). Meanwhile, Fig. 4c shows the





**Figure 5.** The Gaussian deconvolution for the emission spectra of BLSO:0.05Bi<sup>3+</sup> sample under continuous excitation wavelengths from 315 to 370 nm with a step of 5 nm.

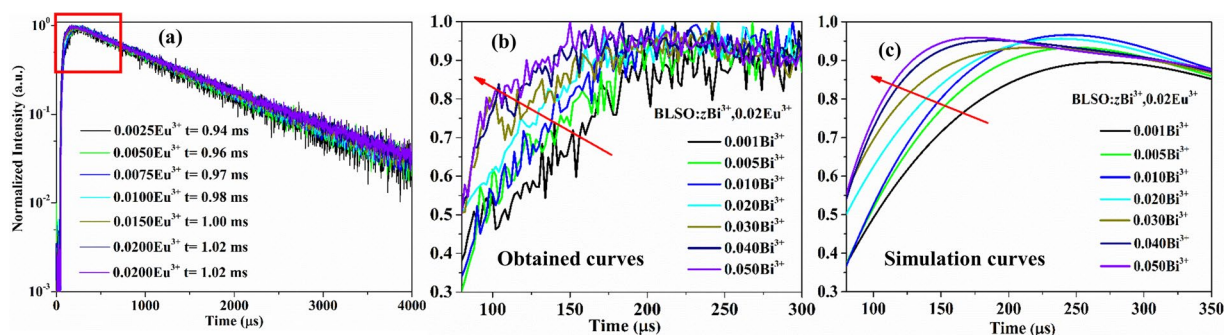


**Figure 6.** Emission spectra of BLSO:0.07Bi<sup>3+</sup>, yEu<sup>3+</sup> ( $y = 0.0025$ – $0.0250$ ) samples excited at 344 nm (a) and 370 nm (b). The inset shows the related CIE chromaticity diagram.

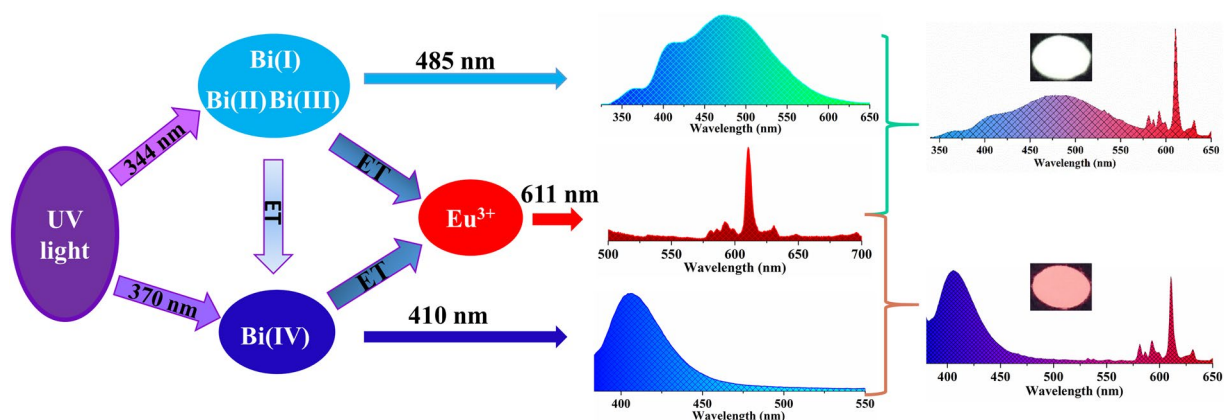
located in asymmetric sites in the BLSO host. It is interesting to note that the combination of these Eu<sup>3+</sup> emission lines with the Bi<sup>3+</sup> emission in the BLSO host is helpful to generate white light performance.

Comparing the emission spectrum of BLSO:0.05Bi<sup>3+</sup> with the excitation spectrum of BLSO:0.005Eu<sup>3+</sup> in Fig. 4a and Fig. S2, there is a significant spectral overlap in the range of 350–500 nm. According to this phenomenon, there may exist energy transfer from Bi<sup>3+</sup> to Eu<sup>3+</sup> in the BLSO host. In order to study the energy transfer from the Bi<sup>3+</sup> to Eu<sup>3+</sup> ions, the emission spectra of the BLSO:0.07Bi<sup>3+</sup>, yEu<sup>3+</sup> ( $y = 0.0025$ – $0.0250$ ) phosphors excited at 344 and 370 nm are shown in Fig. 6a,b, respectively. Obviously, at either excitation wavelength, as the Eu<sup>3+</sup> concentration increases, the emission intensity of Bi<sup>3+</sup> rapidly reduces, while the emission intensity of Eu<sup>3+</sup> gradually increases. In addition, there is no Eu<sup>3+</sup> concentration quenching as  $y$  increases from 0.0025 to 0.025. Based on this, we can clearly deduce the existence of energy transfer from Bi<sup>3+</sup> to Eu<sup>3+</sup> in the BLSO host. The related CIE chromaticity diagram of BLSO:0.07Bi<sup>3+</sup>, yEu<sup>3+</sup> ( $y = 0.0025$ – $0.0200$ ) samples is listed in the inset of Fig. 6. It is found that the location of the color coordinates ( $x$ ,  $y$ ) changes from bluish green to pink across the





**Figure 8.** (a) Decay curves of BLSO:zBi<sup>3+</sup>, 0.02Eu<sup>3+</sup> samples excited at 370 nm and monitored at 611 nm. The obtained curves of enlarged initial rise-up region from 80 to 300 μs (b) and the corresponding simulation curves (c).



**Figure 9.** Energy transfer scheme of generating white light/tunable emissions in Bi<sup>3+</sup> and Eu<sup>3+</sup> co-doped BLSO phosphor upon UV light excitation.

where  $I(t)$  is the luminous intensity at time  $t$ . According to equation (3), the average lifetimes of Bi<sup>3+</sup> were evaluated and listed in Table S2. The lifetimes of Bi<sup>3+</sup> decrease monotonically with an increasing Eu<sup>3+</sup> ion concentrations, strongly supporting energy transfer from Bi<sup>3+</sup> to Eu<sup>3+</sup>.

Using these lifetimes, the energy transfer efficiencies ( $\eta_T$ ) from Bi<sup>3+</sup> to Eu<sup>3+</sup> can be approximately calculated by an equation defined by Paulose *et al.*<sup>29</sup>:

$$\eta_T = 1 - \frac{\tau_S}{\tau_{S_0}} \quad (4)$$

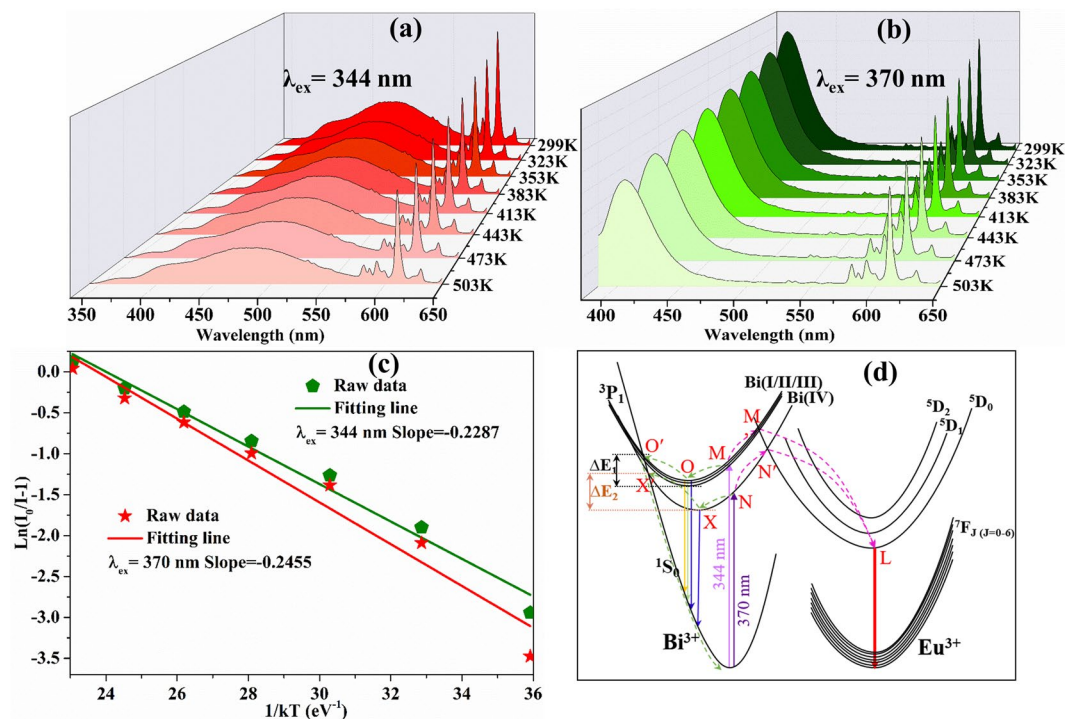
where  $\tau_{S_0}$  and  $\tau_S$  are the intrinsic lifetime of the sensitizer (Bi<sup>3+</sup>) and the lifetime of the sensitizer (Bi<sup>3+</sup>) in the presence of the activator (Eu<sup>3+</sup>), respectively. Using this equation, the  $\eta_T$  values from Bi<sup>3+</sup> to Eu<sup>3+</sup> monitoring at 410 nm emission are calculated to be 12.35%, 21.89%, 28.39%, 32.88%, 42.09%, and 50.84%, while those monitoring at 485 nm emission are 4.26%, 8.11%, 14.70%, 20.29%, 29.25%, and 40.17%.

Figure 8a illustrates the decay curves of the BLSO:zBi<sup>3+</sup>, 0.02Eu<sup>3+</sup> samples excited at 370 nm and monitored at 611 nm. As shown in Fig. 8a, there are two different processes: one is a rise-up process, and the other is a decay process. In the initial rise-up process, energy is trapped by the Bi(4) center and then transfers to the Eu<sup>3+</sup> ions. Figure 8b,c show the obtained curves of the enlarged initial rise-up region from 80 to 300 μs and the corresponding simulation curves, respectively. One can see that the rise-up process shows a high-speed rising due to the increasing Bi<sup>3+</sup> content, which indicates that energy transfer from Bi<sup>3+</sup> to Eu<sup>3+</sup> becomes more efficient. For the decay process, the decay curves show single-exponential decay behavior following the equation:

$$I(t) = I_0 + A \exp(-t/\tau) \quad (5)$$

where  $I(t)$  and  $I_0$  are the luminescence intensities at time  $t$  and  $t = 0$ , respectively;  $\tau$  is the luminescent lifetime;  $A$  is a constant. According to equation (5), the lifetimes of Eu<sup>3+</sup> are calculated to be 0.94, 0.96, 0.97, 0.98, 1.00, 1.02, and 1.02 ms with  $z = 0.001, 0.005, 0.01, 0.02, 0.03, 0.04$ , and  $0.05$ , respectively. In this case, the luminescent lifetime of the activator (Eu<sup>3+</sup>) increases since the Eu<sup>3+</sup> ion emission does not show concentration quenching.

Based on the luminescence and decay behaviors given in Figs 4, 6, 7, and S4, the energy transfer scheme of generating white light/tunable emission in the Bi<sup>3+</sup> and Eu<sup>3+</sup> co-doped BLSO phosphor upon UV light excitation is presented in Fig. 9. Under excitation of 344 nm, the Bi(I), Bi(II) and Bi(III) centers are excited by UV light and



**Figure 10.** Temperature-dependent luminescence properties of BLSO: 0.07Bi<sup>3+</sup>, 0.0075 Eu<sup>3+</sup> phosphor along with temperature increase from 299 to 503 K under 344 nm (a) and 370 nm (b). (c) The plots of  $\ln[I_0/I - 1]$  against  $1/kT$ . (d) The configurational coordinate diagram of the ground and excited states of Bi<sup>3+</sup> and Eu<sup>3+</sup>.

then give a broad blue/green emission band. Simultaneously, due to energy transfer from these three Bi<sup>3+</sup> centers to the Eu<sup>3+</sup> center, warm white light emission can be obtained from the Bi<sup>3+</sup> and Eu<sup>3+</sup> co-doped BLSO phosphor. In addition, under 370 nm excitation, energy is trapped by the Bi(IV) center, giving a strong blue emission. At the same time, by effective energy transfer from the Bi(IV) center to the Eu<sup>3+</sup> center, a tunable emission phosphor from the blue to red region is achieved.

**Thermal Analysis of the Ba<sub>9</sub>Lu<sub>1.92</sub>Si<sub>6</sub>O<sub>24</sub>:0.07Bi<sup>3+</sup>, 0.0075Eu<sup>3+</sup> Phosphor.** It is accepted that the thermal stability of a phosphor is of great significance for its practical applications, including the color rendering index and the light output of w-LEDs<sup>30</sup>. Therefore, Fig. 10a,b show the temperature-dependent luminescence properties of the BLSO: 0.07Bi<sup>3+</sup>, 0.0075Eu<sup>3+</sup> phosphor upon 344 and 370 nm excitations, respectively, with an increasing temperature from 299 to 503 K. We can observe that both emission intensities of the BLSO:0.07Bi<sup>3+</sup>, 0.0075Eu<sup>3+</sup> sample with an increasing temperature gradually decline. Moreover, the emission intensities at 423 K (150 °C) of the BLSO:0.07Bi<sup>3+</sup>, 0.0075Eu<sup>3+</sup> sample under 344 and 370 nm excitations remain at approximately 66.1% and 72.8% of their initial values, respectively. To meet application requirements, the thermal stability of the obtained phosphor must be strengthened. Generally, strengthening of the thermal stability can be achieved by optimizing the preparation conditions to reduce vacancies and improve crystallinity. It is well known that the activation energy ( $E_a$ ) is a good indicator to assess the thermal stability of phosphors<sup>31</sup>. It can be calculated from the Arrhenius equation<sup>32</sup>:

$$\ln\left\{\frac{I_0}{I} - 1\right\} = \ln A - \frac{E_a}{kT} \quad (6)$$

where  $I_0$  and  $I$  are the integrated intensity at room temperature and a particular operating temperatures, respectively;  $E_a$  and  $T$  are the calculated activation energy and the operating temperature (K), respectively;  $A$  and  $k$  are a constant for a certain host and the Boltzmann constant ( $8.62 \times 10^{-5}$  eV K<sup>-1</sup>), respectively. As depicted in Fig. 10c, through a best-fitting of the  $\ln[I_0/I - 1]$  against  $1/kT$  plot using equation (6), the calculated activation energies  $E_a$  are 0.2287 and 0.2455 eV for 344 and 370 nm excitations, respectively. From the above investigation, we can see that the thermal stability of the obtained phosphor excited at 370 nm is more stable than that excited at 344 nm, which is consistent with the calculated results.

The configurational coordinate diagrams of the ground and excited states of Bi<sup>3+</sup> and Eu<sup>3+</sup> as well as the CTB of Eu<sup>3+</sup>-O<sup>2-</sup> are displayed in Fig. 10d. To simplify the structure, we divided the bismuth ions into two types: one for Bi(I), Bi(II) and Bi(III) centers excited at 344 nm; the other for Bi(IV) center excited at 370 nm. Both excitations show similar spectroscopic and energy transfer properties, and thus, the following description is focused on one of them, namely, the 344 nm excitation. Under excitation at 344 nm, the electrons of the Bi(I), Bi(II) and Bi(III) centers absorb the energy and are excited from the <sup>1</sup>S<sub>0</sub> ground state to the <sup>3</sup>P<sub>1</sub> excited state at room







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